2SB0943 (2SB943)

Silicon PNP epitaxial planar type

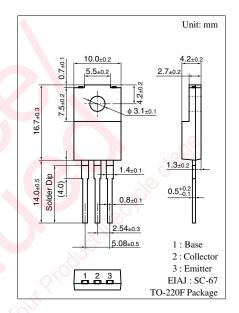
For power switching Complementary to 2SD1268

■ Features

- \bullet Low collector to emitter saturation voltage $V_{\text{CE(sat)}}$
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector to base voltage	V _{CBO}	-130	V	
Collector to emitter voltage	V _{CEO}	-80	V	
Emitter to base voltage	V _{EBO}	-7	V	
Peak collector current	I_{CP}	-6	A	
Collector current	I_{C}	-3	A	
Collector power $T_C = 25^{\circ}C$	P _C	30	W	
dissipation $T_a = 25^{\circ}C$		2	10,	
Junction temperature	T _j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



■ Electrical Characteristics T_C = 25°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -100 \text{ V}, I_{E} = 0$	7.7		-10	μΑ
Emitter cutoff current	I_{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$			-50	μΑ
Collector to emitter voltage	V _{CEO}	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = 0$	-80			V
Forward current transfer ratio	h _{FE1}	$V_{CE} = -2 \text{ V}, I_{C} = -0.1 \text{ A}$	45			
	h _{FE2} *	$V_{CE} = -2 \text{ V}, I_C = -0.5 \text{ A}$	90		260	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = -2 \text{ A}, I_B = -0.1 \text{ A}$			- 0.5	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_C = -2 \text{ A}, I_B = -0.1 \text{ A}$			-1.5	V
Transition frequency	f_T	$V_{CE} = -10 \text{ V}, I_{C} = -0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_C = -0.5 \text{ A}, I_{B1} = -50 \text{ mA}, I_{B2} = 50 \text{ mA}$		0.3		μs
Storage time	t _{stg}			1.1		μs
Fall time	t _f			0.3		μs

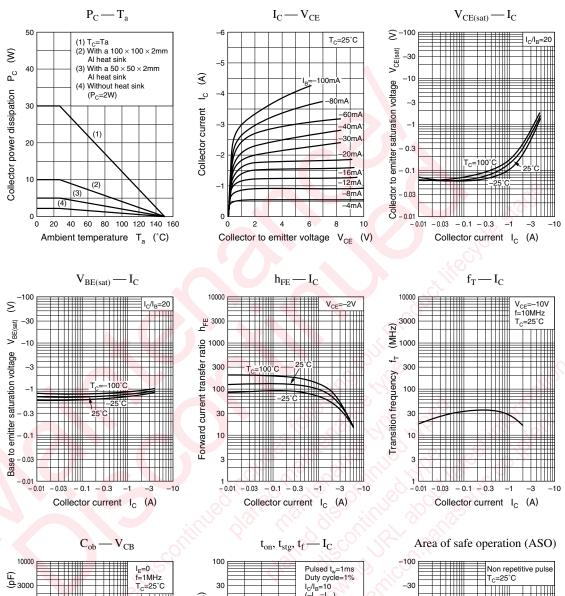
Note) *: Rank classification

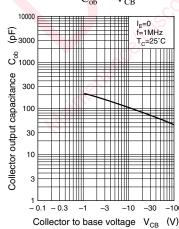
Rank	Q	Р
h _{FE2}	90 to 180	130 to 260

Note.) The Part number in the Parenthesis shows conventional part number.

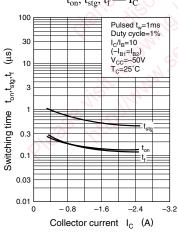
Panasonic 1

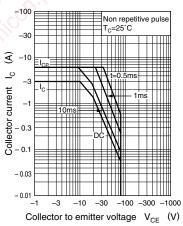
2SB0943 Power Transistors



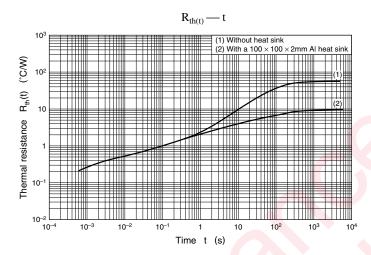


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Power Transistors 2SB0943



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